NSN 5961-01-041-6812

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AeroBase Group

View Online at https://aerobasegroup.com/nsn/5961-01-041-6812

Inclosure Material:

Plastic

Overall Length:

Between 0.360 inches and 0.400 inches

Overall Height:

Between 0.170 inches and 0.190 inches

Overall Width:

Between 0.285 inches and 0.315 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

-30.0 collector to emitter voltage/static/base open and -5.0 emitter to base voltage, static, collector open and -45.0 collector to emitter voltage, dc with base short-circuited to emitter

Current Rating Per Characteristic:

3.00 amperes source cutoff current

Power Rating Per Characteristic:

12.5 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

165.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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